NSN 5962-01-332-1179

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View Online at https://aerobasegroup.com/nsn/5962-01-332-1179 **Overall Height:** 0.312 inches **Body Length:** Between 1.235 inches and 1.285 inches **Body Width:** Between 0.515 inches and 0.600 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 790.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and programmable and ultraviolet erasable and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.3 volts power source and 6.0 volts power source **Time Rating Per Chacteristic:** 250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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